

Diode Module with Brake

Diode:1600V / 75A, IGBT:1400A/50A

■ Features

- Compact Package
- P.C. Board Mount Module
- Converter Diode Bridge Dynamic Brake Circuit

■ Applications

- Inverter for Motor Drive
- AC and DC Servo Drive Amplifier
- Uninterruptible Power Supply

■ Maximum ratings and characteristics

● Absolute maximum ratings (Tc=25°C unless without specified)

Item	Symbol	Condition	Rating	Unit		
Converte	Repetitive peak reverse voltage	V _{RRM}	1600	V		
	Non-repetitive peak reverse voltage	V _{RSM}	1760	V		
	Average output current	I _o	50Hz/60Hz sine wave T _c =115°C	75	A	
	One cycle surge current	I _{FSM}	From rated load	600	A	
	I _{pt}	I _{pt}	From rated load	1440	A²s	
	Operation junction temperature	T _j		-40 to +125	°C	
Brake	Collector-Emitter voltage	V _{CES}	1400	V		
	Gate-Emitter voltage	V _{GES}	±20	V		
	Collector current	I _c	DC	T _c =25°C 50	A	
				T _c =75°C 35		
		I _{CP}	1ms	T _c =25°C 100	A	
				T _c =75°C 70		
	Collector power dissipation	P _c	1 device	240	W	
	Repetitive peak reverse voltage	V _{RRM}		1400	V	
	Operation junction temperature	T _j		+150	°C	
Storage junction temperature			T _{sg}	AC : 1 minute	-40 to +125	°C
Isolation voltage			V _{iso}	M5 screw	3000	V
Mounting screw torque					2.0 to 2.5	N·m

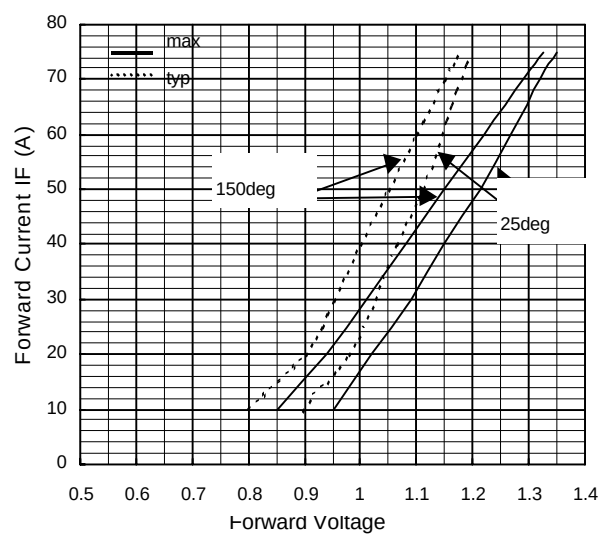
● Electrical characteristics (Tj=25°C unless otherwise specified)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Co.	Forward voltage	V _{FM}	Tj=25°C, I _{FM} =75A		1.35	V
	Reverse current	I _{RRM}	Tj=150°C, V _R =V _{RRM}		15	mA
	Zero gate voltage Collector current	I _{CES}	V _{GE} =0V. V _{CE} =1400V		1.0	mA
	Gate-Emitter leakage current	I _{GES}	V _{CE} =0V. V _{GE} =±20V		200	nA
	Collector-Emitter saturation voltage	V _{CE(sat)}	V _{GE} =15V. I _c =35A	2.4	2.8	V
Brake	Turn-on time	ton	V _{cc} =800V	0.35	1.2	μs
		tr	I _c =35A	0.25	0.6	
	Turn-off time	toff	V _{GE} =±15V	0.45	1.0	
		tf	R _G =33ohm	0.08	0.3	
	Reverse current	I _{RRM}			1.0	mA

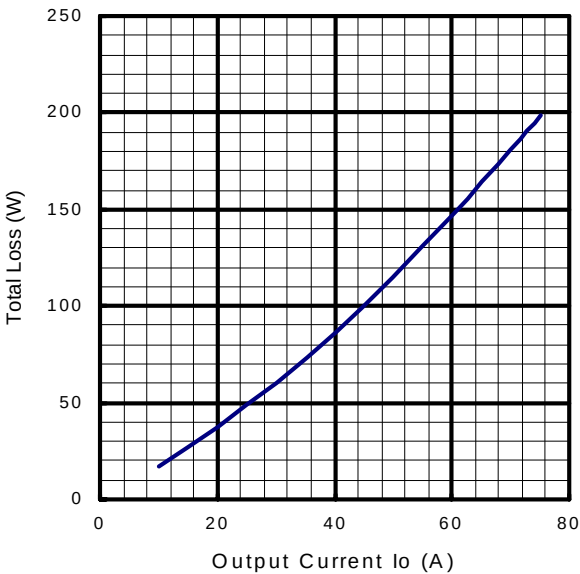
● Thermal characteristics

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Thermal resistance	R _{th(j-c)}	Converter	Per total loss		0.16	°C/W
			Per each device		0.96	
		Brake IGBT (1 device)			0.70	
Thermal Resistance(Case to fine)	R _{th(c-f)}	with thermal compound			0.08	°C/W

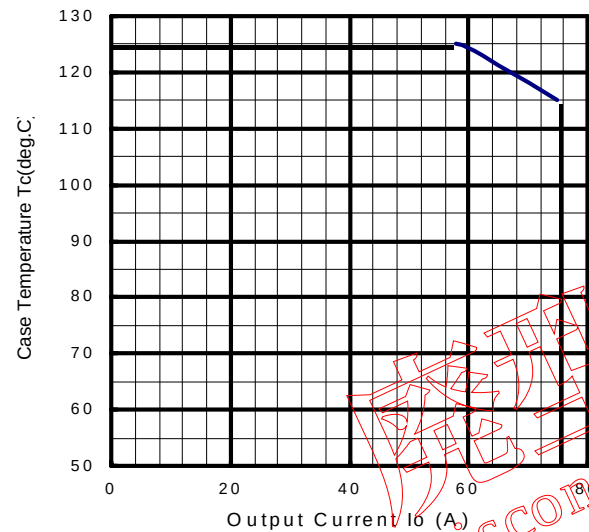
Forward Characteristics



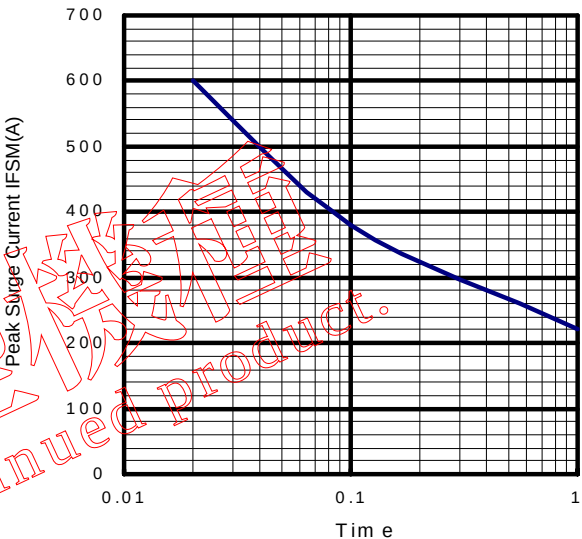
Output Current - Total Loss



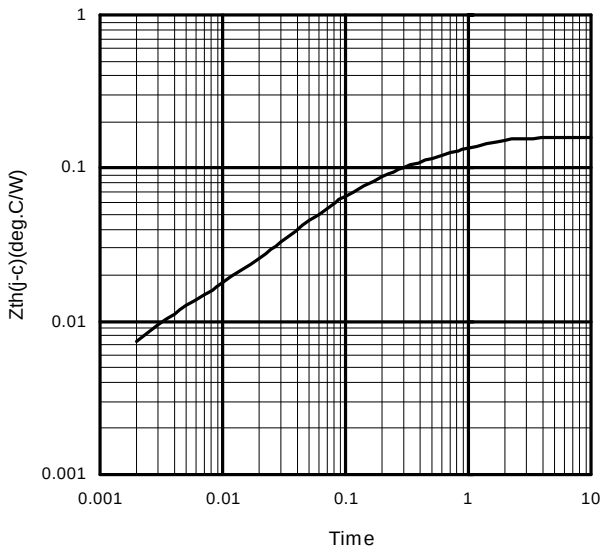
Output Current - Case Temperature



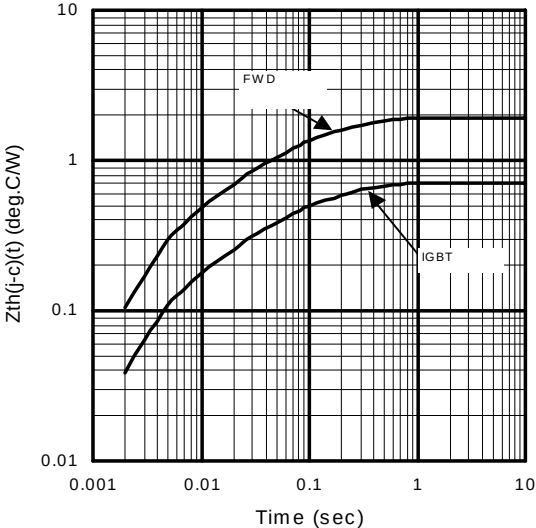
Surge Current

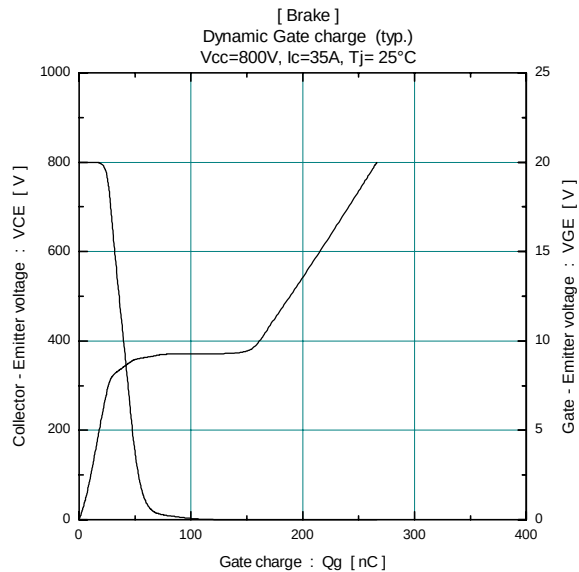
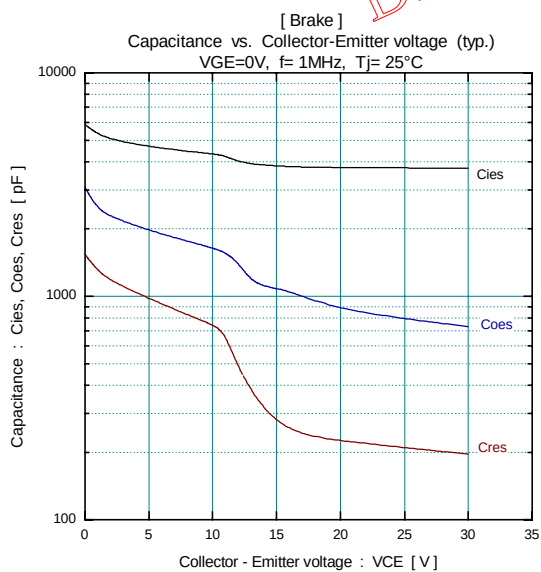
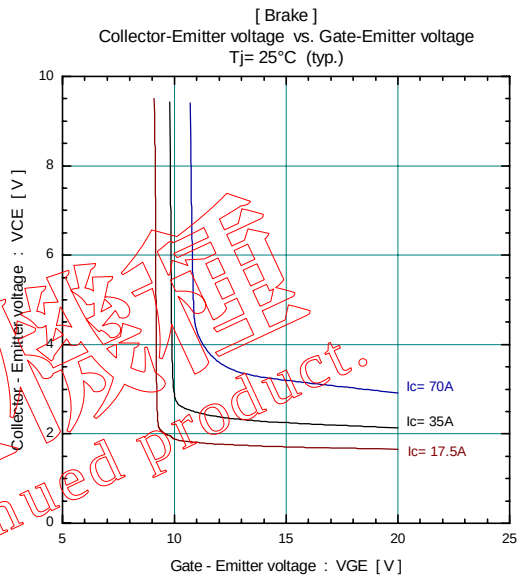
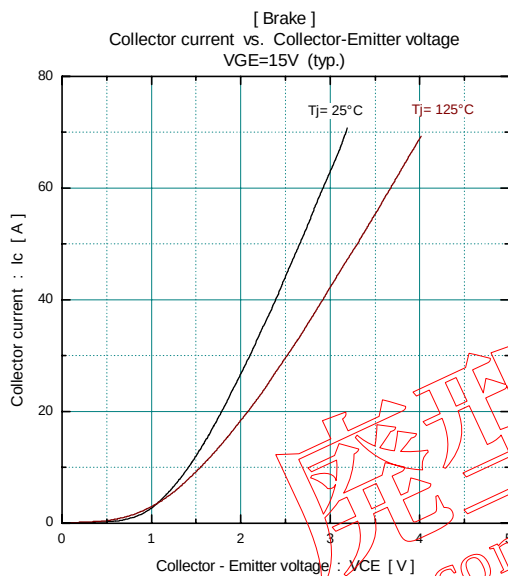
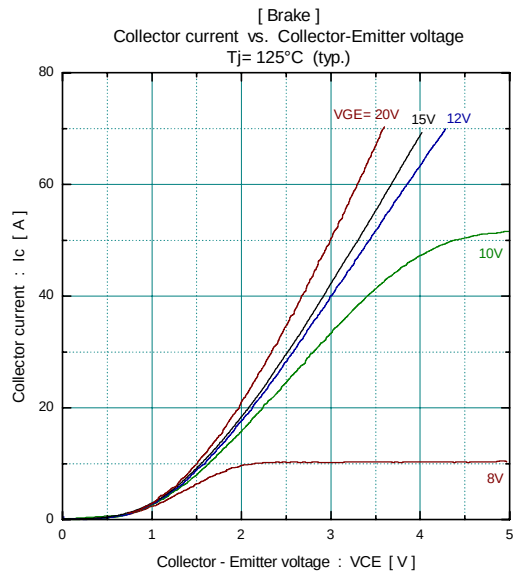
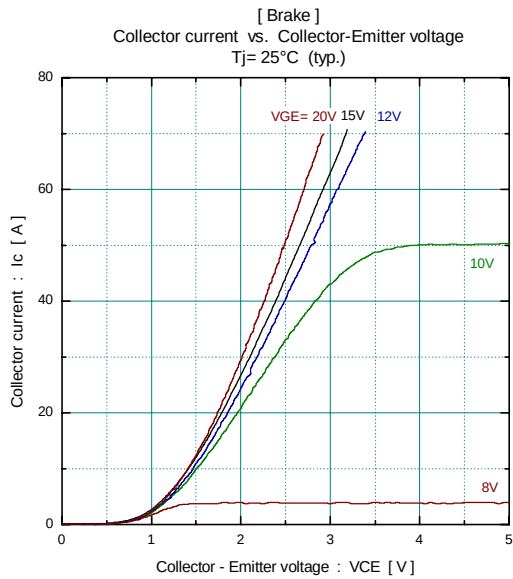


Transient Thermal Impedance

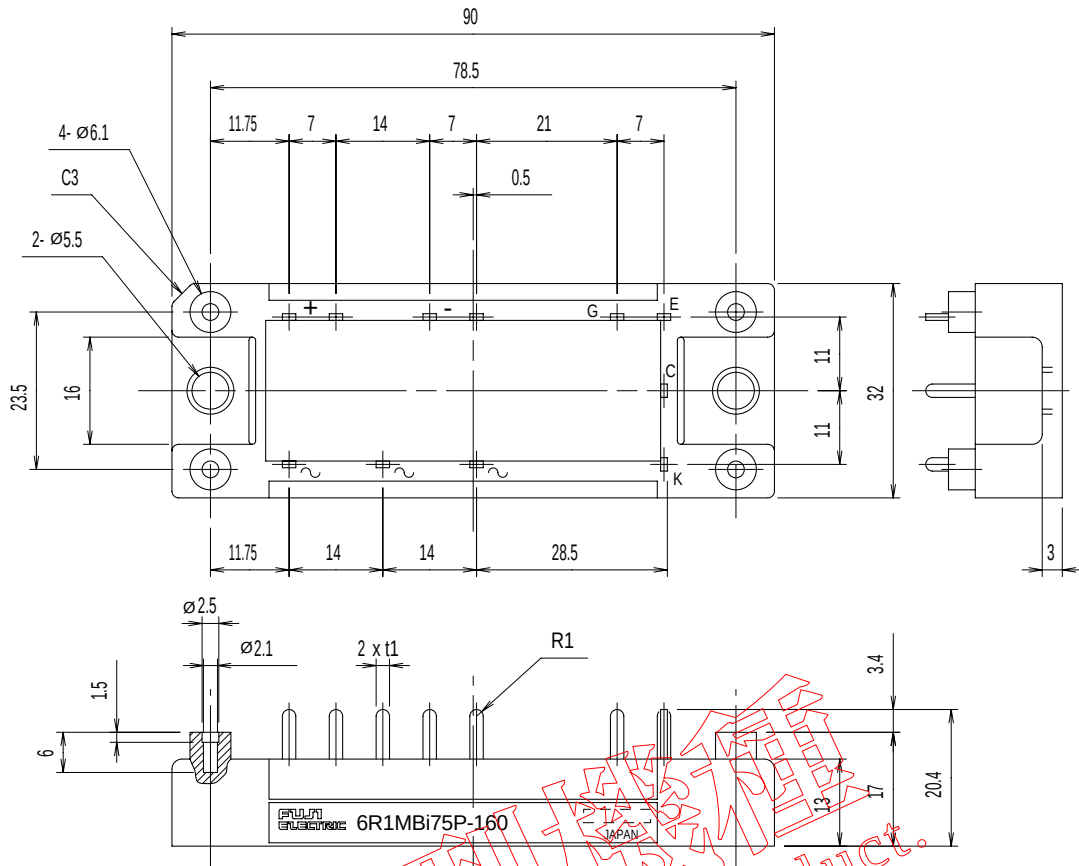


[Brake] Transient Thermal Impedance





■ Outline Drawings, mm



■ Equivalent Circuit Schematic

